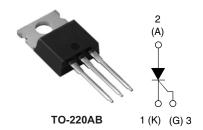




Vishay High Power Products

Phase Control SCR, 25 A



PRODUCT SUMMARY				
V _T at 16 A	< 1.25 V			
I _{TSM}	300 A			
V _{RRM}	800/1200 V			

DESCRIPTION/FEATURES



The 25TTS.. High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °

RoHS*

used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level and lead (Pb)-free ("PbF" suffix).

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS			
Capacitive input filter T _A = 55 °C, T _J = 125 °C, common heatsink of 1 °C/W	18	22	А			

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I _{T(AV)}	Sinusoidal waveform	16	۸			
I _{RMS}		25	Α			
V _{RRM} /V _{DRM}		800/1200	V			
I _{TSM}		300	A			
V _T	16 A, T _J = 25 °C	1.25	V			
dV/dt		500	V/µs			
dl/dt		150	A/μs			
T _J		- 40 to 125	°C			

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA					
25TTS08PbF	800	800	10					
25TTS12PbF	1200	1200	10					

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CO.	TEST CONDITIONS		VALUES		
PARAMETER	SYMBOL TEST CONDITIONS		NUTTIONS	TYP.	MAX.	UNITS	
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 180° conduc	tion half sine wave	16			
Maximum RMS on-state current	I _{RMS}			2	5	A	
Maximum peak, one-cycle,	I _{TSM}	10 ms sine pulse, rated \	V _{RRM} applied	30	00		
non-repetitive surge current	ITSM	10 ms sine pulse, no volt	tage reapplied	3	50		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied		4	50	A ² s	
waxiiiluiii i tioi iusiiig	I-ί	10 ms sine pulse, no volt	630		Α 5		
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		6300		A²√s	
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C		1.	25	V	
On-state slope resistance	r _t	T _{.I} = 125 °C		12.0		$m\Omega$	
Threshold voltage	$V_{T(TO)}$	1j = 125 O		1	.0	V	
Maximum reverse and direct leakage current	1/1	T _J = 25 °C	$V_{B} = Rated V_{BRM}/V_{DRM}$	0	.5		
waxiinum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	VR = nateu VRRM/VDRM	1	0	mA	
Holding current	Ι _Η	Anode supply = 6 V, resistive load, initial I _T = 1 A		-	100	IIIA	
Maximum latching current	IL	Anode supply = 6 V, resistive load		20	00		
Maximum rate of rise of off-state voltage	dV/dt			50	00	V/µs	
Maximum rate of rise of turned-on current	dl/dt			150		A/μs	

TRIGGERING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak gate power	P_{GM}		8.0	W			
Maximum average gate power	$P_{G(AV)}$		2.0	VV			
Maximum peak positive gate current	+ I _{GM}		1.5	Α			
Maximum peak negative gate voltage	- V _{GM}		10	V			
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	60	mA			
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	45				
		Anode supply = 6 V, resistive load, T _J = 125 °C	20				
	V _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5				
Maximum required DC gate voltage to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	0 V			
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V			
Maximum DC gate voltage not to trigger	V_{GD}	T = 105 °C V = Poted volue	0.25				
Maximum DC gate current not to trigger	I_{GD}	T _J = 125 °C, V _{DRM} = Rated value	2.0	mA			

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9			
Typical reverse recovery time	t _{rr}	T - 105 °C	4	μs		
Typical turn-off time	t _q	T _J = 125 °C	110			

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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	1	T_J , T_{Stg}		- 40 to 125	°C	
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.1		
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
minin				6 (5)	kgf · cm	
Mounting torque ——	maximum			12 (10)	(lbf ⋅ in)	
Marking device			Coop at the TO 200AB	25T	ΓS08	
			Case style TO-220AB		25TTS12	

Vishay High Power Products Phase Control SCR, 25 A



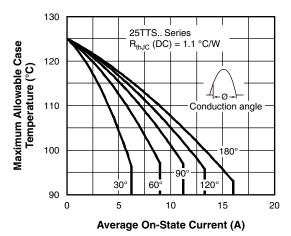


Fig. 1 - Current Rating Characteristics

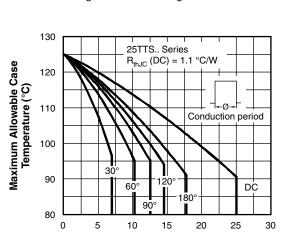


Fig. 2 - Current Rating Characteristics

Average On-State Current (A)

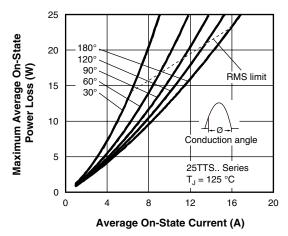


Fig. 3 - On-State Power Loss Characteristics

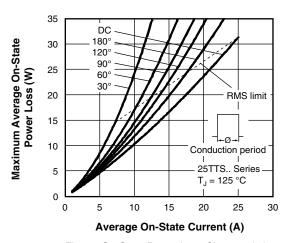
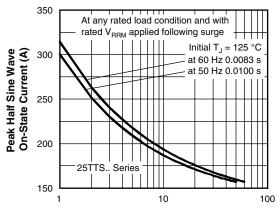


Fig. 4 - On-State Power Loss Characteristics



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

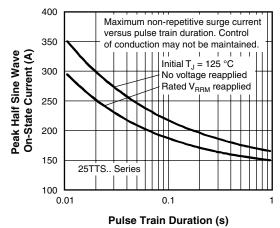


Fig. 6 - Maximum Non-Repetitive Surge Current



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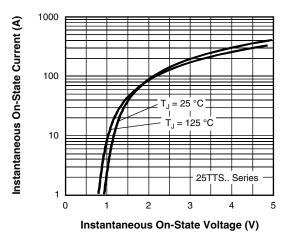


Fig. 7 - On-State Voltage Drop Characteristics

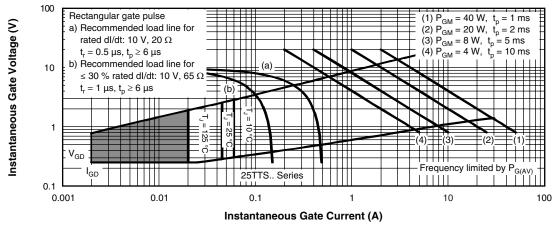


Fig. 8 - Gate Characteristics

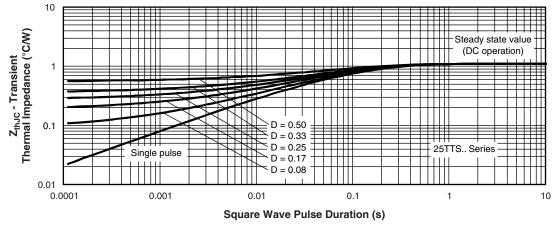


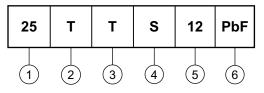
Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

Vishay High Power Products Phase Control SCR, 25 A



ORDERING INFORMATION TABLE

Device code



1 - Current rating (25 = 25 A)

2 - Circuit configuration:

T = Single thyristor

3 - Package:

T = TO-220AB

4 - Type of silicon:

S = Standard recovery rectifier

08 = 800 V 12 = 1200 V

Voltage rating

None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95222					
Part marking information http://www.vishay.com/doc?95225					

www.vishay.com

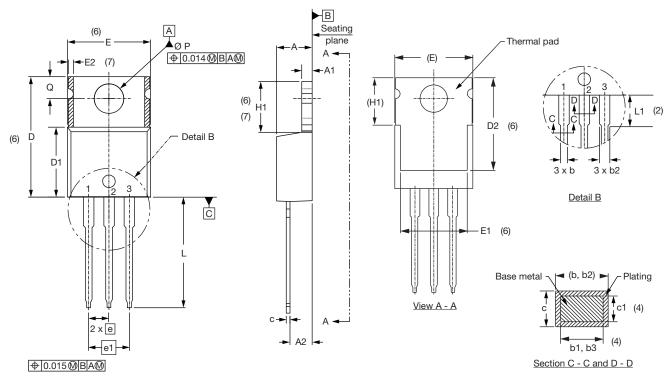
For technical questions, contact: diodes-tech@vishay.com



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

Lead assignments

<u>Diodes</u>

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MIN. MAX.	
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Legal Disclaimer Notice



Vishay

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